# NSN 5962-01-307-9929

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## **Overall Height:**

Between 0.357 inches and 0.432 inches

## **Body Length:**

1.490 inches

## Body Width:

Between 0.500 inches and 0.610 inches

## **Body Height:**

Between 0.172 inches and 0.217 inches

## **Maximum Power Dissipation Rating:**

1.0 watts

## **Operating Tempurature Range:**

-55.0/+125.0 degrees celsius

## Storage Tempurature Range:

-65.0/+150.0 degrees celsius

### **Features Provided:**

Electrostatic sensitive and hermetically sealed and burn in and programmable and ultraviolet erasable

### Inclosure Material:

Ceramic

## **Inclosure Configuration:**

Dual-in-line

## Output Logic Form:

N-type metal oxide-semiconductor logic

#### **Input Circuit Pattern:**

16 input

## **Case Outline Source And Designator:**

D-10 mil-m-38510

## **Terminal Surface Treatment:**

Solder

## Voltage Rating And Type Per Characteristic:

7.0 volts power source

## **Time Rating Per Chacteristic:**

200.00 nanoseconds propagation delay time, low to high level output and 200.00 nanoseconds propagation delay time, high to low level

output

## Memory Device Type:

Rom

## **Memory Capacity:**

Unknown

## **Test Data Document:**

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

## Terminal Type And Quantity:

28 printed circuit

## Shelf Life:

N/a

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Demilitarization:

Yes - demil/mli

Fiig:

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